

# ISL8240MEVAL4Z Dual 20A/Optional 40A Cascadable Evaluation Board Setup Procedure

The ISL8240MEVAL4Z is a complete, dual step-down switching mode DC/DC module. The dual outputs can easily be paralleled for single-output, high current use. It is easy to apply this high power, current sharing DC/DC power module to power hungry datacom, telecom and FPGA applications. All that is needed in order to have a complete, dual 20A design ready for use are the  $\underline{\text{ISL8240M}}$ , a few passive components and  $V_{\text{OUT}}$  setting resistors.

The simplicity of the ISL8240M is its off-the-shelf, unassisted implementation. Patented current sharing in multi phase operation greatly reduces ripple currents, BOM costs and complexity. The ISL8240M has a thermally enhanced, compact 17mmx17mmx7.5mm QFN package that operates at full load and over-temperature. Easy access to all pins, with few external components, reduces PCB design to a component layer and a simple ground layer.

This ISL8240MEVAL4Z evaluation board is designed for dual 20A output applications. Optionally, this board can easily be converted for 40A single output use. Multiple ISL8240MEVAL4Z boards can be cascadable through the SYNC and CLKOUT pins to operate with phase shifting, for paralleling or multiple output use. The input voltage of this board is 4.5V to 20V and the default outputs on this board are set at 1.0V and 1.5V.

# **Recommended Equipment**

- OV to 20V power supply with at least 5A source current capability
- Electronic load capable of sinking current up to 40A
- Digital Multimeters (DMMs)
- · 100MHz quad-trace oscilloscope

### **Quick Start**

For dual output operation, the inputs are BA7 (VIN1), BA8 (GND), BA3 (VIN2) and BA4 (GND). The outputs are BA5 (VOUT1), BA6 (GND), BA1 (VOUT2) and BA2 (GND).

For paralleled single output operation, the inputs are BA7 (VIN1) and BA8 (GND). The outputs are BA5 (VOUT1) and BA6 (GND) with BA5 and BA1 shorted.

# **Ordering Information**

| PART NUMBER    | DESCRIPTION      |  |  |  |  |
|----------------|------------------|--|--|--|--|
| ISL8240MEVAL4Z | Evaluation Board |  |  |  |  |

#### References

• ISL8240M datasheet.



FIGURE 1. ISL8240MEVAL4Z BOARD IMAGE

#### **Application Note 1922**

#### **Dual Output Mode**

- 1. Connect a power supply capable of sourcing at least 5A to inputs BA7 (VIN1), BA8 (GND), BA3 (VIN2) and BA4 (GND) of the ISL8240MEVAL4Z evaluation board, with a voltage between 4.5V to 20V. VIN1 and VIN2 can be different with R<sub>18</sub> and R<sub>19</sub> open.
- 2. Connect an electronic load or device to be powered to the outputs BA5 (VOUT1), BA6 (GND), BA1 (VOUT2) and BA2 (GND) of the board. All connections, especially the low voltage, high current VOUT lines, should be able to carry the desired load current and should be made as short as possible
- 3. Make sure that the setup is connected correctly. Turn on the power supply. If the board is working properly, the green LED will illuminate; if not, the red LED will illuminate (recheck the wire/jumper connections in this case). Measure the output voltages, V<sub>OUT1</sub>, which should be at 1.0V and V<sub>OUT2</sub>, which should be at 1.5V
- 4. If different output voltages are desired, board resistors can be exchanged to provide the desired V<sub>OUT</sub>. Please refer to Table 1 for R<sub>2</sub>/R<sub>4</sub> resistor values, which can be used to produce different output voltages.

The switching frequency is set to 500kHz by default. The switching frequency can be adjusted, as recommended in <u>Table 1</u>. By changing the resistor R<sub>FSET</sub>, the desired frequency can be adjusted. If the output voltage is set to ≥1.5V, the output current will need to be derated at certain conditions to allow for safe operation. Please refer to the ISL8240M datasheet.

TABLE 1. VALUE OF BOTTOM RESISTOR (TOP RESISTOR R<sub>1</sub>,  $R_3 = 1k\Omega$ ) AND FREQUENCY SELECTION FOR DIFFERENT **OUTPUT VOLTAGES** 

| V <sub>OUT</sub> (V) | R <sub>2</sub> /R <sub>4</sub><br>(Ω) | FREQUENCY<br>(kHz) | $R_{FSET}(k\Omega)$<br>( $V_{IN}$ = 12V) |
|----------------------|---------------------------------------|--------------------|--|
| 1.0                  | 1500                                  | 500                | 237                                      |
| 1.2                  | 1000                                  | 550                | 174                                      |
| 1.5                  | 665                                   | 600                | 140                                      |
| 1.8                  | 499                                   | 650                | 115                                      |
| 2.5                  | 316                                   | 700                | 100                                      |

#### **Optional Paralleled Single Output Mode**

- 1. To set up the parallel mode, short JP1 (ENC), JP2 (VMON) and JP3 (COMP) with a jumper. To set up 180° interleaving phase between 2 channels, short the MODE pin and GND pin of JP6 with a jumper.
- 2. Remove  $R_9$  and  $R_{13}$ . Change  $R_{14}$  to  $0\Omega$ . Change  $R_{18}$  and  $R_{19}$ to  $0\Omega$ . Short VOUT1 to VOUT2 using short wires or copper straps. Add C2 for a 470pF capacitor.
- 3. Connect a power supply capable of sourcing at least 5A to the inputs BA7 (VIN1), BA8 (GND), BA3 (VIN2) and BA4 (GND) of the ISL8240MEVAL4Z evaluation board, with a voltage between 4.5V to 20V. VIN1 and VIN2 need to be shorted together.

- 4. Connect an electronic load or the device to be powered to the outputs BA5 (VOUT1) and BA6 (GND) of the board. All connections, especially the low voltage, high current Voltage lines, should be able to carry the desired load current and should be made as short as possible.
- 5. Make sure the setup is connected correctly prior to applying any power to the board. Adjust the power supply to 12V and turn on the input power supply. If the board is working properly, the green LED will illuminate; if not, the red LED will illuminate (recheck the wire/jumper connections in this case). Measure the output voltages, V<sub>OUT1</sub>, which should be at 1.0V.
- 6. Apply any load that is less than 40A for normal steady state operation. Refer to Table 1 to change the output voltage by changing resistor R<sub>2</sub>.

**TABLE 2. BOARD CONFIGURATION FOR SINGLE OUTPUT 40A** APPLICATION

|        | ENC  | VMON | MODE | СОМР | R9   | R13  | R14  |
|--------|------|------|------|------|------|------|------|
| Dual   | OPEN | OPEN | OPEN | OPEN | 0    | 0    | OPEN |
| Single | ON   | ON   | ON   | ON   | OPEN | OPEN | 0    |

For optimized performance of a 2-phase single output application of the ISL8240M, please refer to application note AN1923.

#### **Optional Cascadable Mode**

Cascadable mode is needed when multiple evaluation boards are used for paralleling or multiple output use. Follow the steps shown below:

- 1. In order to generate CLKOUT at a shifted phase clock signal, the control loop of VOUT2 needs to be disabled by connecting VSEN2- to VCC.
- 2. Program MODE and VSEN2+ pin voltages to set the CLKOUT signal and the shifted degrees between two phases on the board (refer to Table 3 on page 4).
- 3. Use a coaxial cable to connect CLKOUT (J5) to SYNC (J2) of the next evaluation board, which can be programmed for parallel or dual output use.
- 4. If the second board is programmed for parallel use, the ISHARE pins of the first and second boards need to be tied together. Using two twisted wires, short two different jumpers of JP7 (ISHARE/SGND) on two evaluation boards. Add 1nF capacitors of C<sub>14</sub> for different boards to decouple the noise.
- 5. If the third board is used in cascadable mode, the second board can only be used in the parallel mode to generate the CLKOUT signal for the SYNC pin on the third board.
- 6. Follow the instructions from Steps 1 through 5 for more cascadable boards.

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#### **Application Note 1922**

#### **Evaluation Board Information**

The evaluation board size is 114.3mmx76.2mm. It is a 4-layer board, containing 2-ounce copper on the top and bottom layers and 2-ounce copper on all internal layers. The board can be used as a dual 20A reference design. Refer to <u>"Layout" on page 6</u>. The board is made of FR4 material and all components, including the solder attachment, are lead-free.

#### **Thermal Considerations and Current Derating**

For high current applications, board layout is very critical in order to make the module operate safely and deliver maximum allowable power. To carry large currents, the board layout needs to be designed carefully to maximize thermal performance. To achieve this, use sufficient trace width, copper weight and the proper connectors.

This evaluation board is designed for running dual 20A at room temperature without additional cooling systems needed. However, if the output voltage is increased or the board is operated at elevated temperatures, then the available current is derated. Refer to the derated current curves in the <a href="ISL8240M">ISL8240M</a> datasheet to determine the output current available.

For layout of designs using the ISL8240M, the thermal performance can be improved by adhering to the following design tips:

- Use the top and bottom layers to carry the large current. VOUT1, VOUT2, Phase 1, Phase 2, PGND, VIN1 and VIN2 should have large, solid planes. Place enough thermal vias to connect the power planes in different layers under and around the module.
- 2. Phase 1 and Phase 2 pads are switching nodes that generate switching noise. Keep these pads under the module. For noise-sensitive applications, it is recommended to keep phase pads only on the top and inner layers of the PCB; do not place phase pads exposed to the outside on the bottom layer of the PCB. To improve the thermal performance, the phase pads can be extended in the inner layer, as shown in Phase 1 and Phase 2 pads on layer 2 (Figure 5) for this dual 20A evaluation board. Make sure that layer 1 and layer 3 have the GND layers to cover the extended areas of phase pads at layer 2 to avoid noise coupling.
- Place the modules evenly on the board and leave enough space between modules. If the board space is limited, try to put the modules with low power loss closely together (i.e. low V<sub>OUT</sub> or I<sub>OUT</sub>) while still separating the module with high power loss
- 4. If the ambient temperature is high or the board space is limited, airflow is needed to dissipate more heat from the modules. A heatsink can also be applied to the top side of the module to further improve the thermal performance (heatsink recommendation: Aavid Thermalloy, part number 375424B00034G, www.aavid.com).

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# **Application Note 1922**

#### **TABLE 3. ISL8240M OPERATION MODES**

| 1ST MODULE (I = INPUT; O = OUTPUT; I/O = INPUT AND OUTPUT, BI-DIRECTION)           |   |         |                         |                 |                 |   |                        | MODES OF  |  |   |   |   |
|--|---|---------|-------------------------|-----------------|-----------------|---|------------------------|---|--|---|---|---|
| MODE   | EN1/FF1<br>(I)  | EN2/FF2 | VSEN2-<br>(I)           | MODE<br>(I)     | VSEN2+<br>(I)   | CLKOUT/REFIN<br>WRT 1 <sup>ST</sup><br>(I OR 0) | VMON2<br>(Note 2)      | VMON1<br>OF 2 <sup>ND</sup><br>MODULE<br>(Note 2) | 2 <sup>ND</sup> CHANNEL<br>WRT 1 <sup>ST</sup> (0)<br>(Note 1) | OPERATION<br>MODE<br>OF 2 <sup>ND</sup><br>MODULE | OPERATION<br>MODE<br>OF 3 <sup>RD</sup><br>MODULE | OUTPUT<br>(see Description<br>for details)          |
| 1  | 0   | 0       | -                       | -               | -               | -   | -                      | -   | -  | -   | -   | Disabled  |
| 2A   | 0   | 1       | Active                  | Active          | Active          | -   | Active                 | -   | VMON1 =<br>VMON2 to<br>Keep PGOOD<br>Valid                     | -   | -   | Single Phase  |
| 2B   | 1   | 0       | -                       | -               | -               | -   | -                      | -   | VMON1 =<br>VMON2 to<br>Keep PGOOD<br>Valid                     | -   | -   | Single Phase  |
| ЗА   | 1   | 1       | <v<sub>CC -0.7V</v<sub> | Active          | Active          | 29% to 45%<br>of V <sub>CC</sub> (I)            | Active                 | -   | 0°   | -   | -   | Dual Regulator                                      |
| 3B   | 1   | 1       | <v<sub>CC -0.7V</v<sub> | Active          | Active          | 45% to 62% of V <sub>CC</sub> (I)               | Active                 | -   | 90°  | -   | -   | Dual Regulator                                      |
| 3C   | 1   | 1       | <v<sub>CC -0.7V</v<sub> | Active          | Active          | >62% of V <sub>CC</sub> (I)                     | Active                 | -   | 180°   | -   | -   | Dual Regulator                                      |
| 4  | 1   | 1       | <v<sub>CC -0.7V</v<sub> | Active          | Active          | <29% of V <sub>CC</sub> (I)                     | Active                 | -   | -60°   | -   | -   | DDR Mode  |
| 5A   | 1   | 1       | V <sub>CC</sub>         | GND             | -               | 60°   | VMON1<br>or<br>Divider | -   | 180°   | -   | -   | 2-Phase   |
| 5B   | 1   | 1       | V <sub>cc</sub>         | GND             | 1               | 60°   | Divider                | Divider   | 180°   | 5B  | 5B  | 6-Phase   |
| 5C   | 1   | 1       | V <sub>cc</sub>         | GND             | -               | 60°   | VMON1<br>or<br>Divider | Active  | 180°   | 5C  | 5C  | 3 Outputs   |
| 6  | 1   | 1       | V <sub>cc</sub>         | V <sub>cc</sub> | GND             | 120°  | 1kΩ                    | Active  | 240°   | 2B  | -   | 3-Phase   |
| 7A   | 1   | 1       | V <sub>CC</sub>         | V <sub>CC</sub> | V <sub>CC</sub> | 90°   | 1kΩ                    | Divider   | 180°   | 7A  | -   | 4-Phase   |
| 7B   | 1   | 1       | V <sub>cc</sub>         | v <sub>cc</sub> | V <sub>cc</sub> | 90°   | 1kΩ                    | Active  | 180°   | 7В  | -   | 2 Outputs<br>(1 <sup>st</sup> module in<br>Mode 7A) |
| 7C   | 1   | 1       | V <sub>CC</sub>         | V <sub>CC</sub> | V <sub>CC</sub> | 90°   | <b>1</b> kΩ            | Active  | 180°   | 3, 4  | -   | 3 Outputs<br>(1 <sup>st</sup> module in<br>Mode 7A) |
| 8 Cascaded Module Operation MODEs 5B+5B+7A+5B+5B+5B/7A, No External Clock Required |   |         |                         |                 |                 |   |                        |   |  | 12-Phase  |   |   |
| 9  | External Clock or External Logic Circuits Required for Equal Phase Interval |         |                         |                 |                 |   |                        |   |  |   |   | 5, 7, 8, 9, 10,<br>11, or<br>(PHASE >12)            |

<sup>1. &</sup>quot;2ND CHANNEL WRT 1ST" means "second channel with respect to first;" in other words, Channel 2 lags Channel 1 by the degrees specified in this column. For example, 90° means Channel 2 lags Channel 1 by 90°; -60° means Channel 2 leads Channel 1 by 60°.

<sup>2. &</sup>quot;VMON1" means that the pin is tied to the VMON1 pin of the same module.

<sup>&</sup>quot;Divider" means that there is a resistor divider from VOUT to SGND; refer to Figure 25 in the ISL8240M datasheet.

<sup>&</sup>quot; $1k\Omega$ " means that there is a  $1k\Omega$  resistor connecting the pin to SGND; refer to Figure 23 in the ISL8240M datasheet.

# **ISL8240MEVAL4Z Board Schematic**

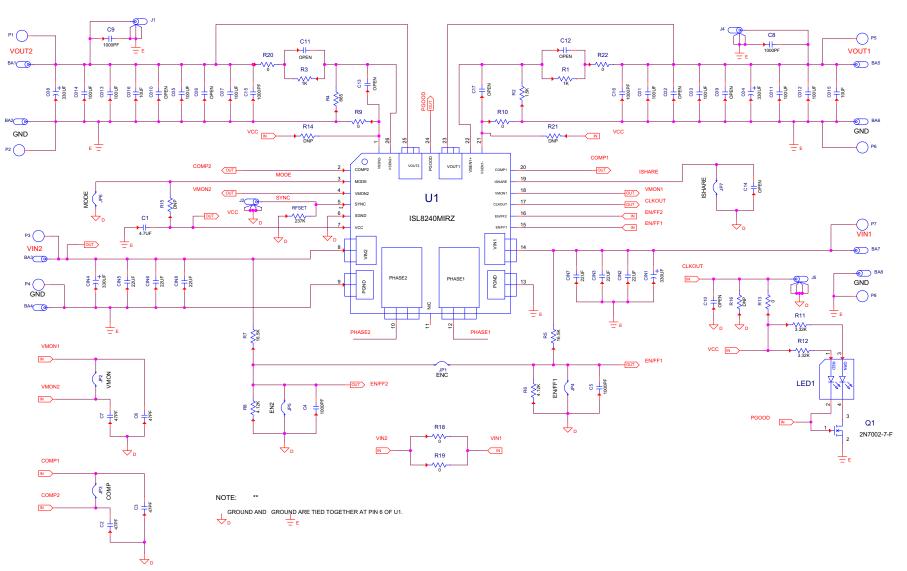


FIGURE 2. ISL8240MEVAL4Z BOARD SCHEMATIC

0

# Layout

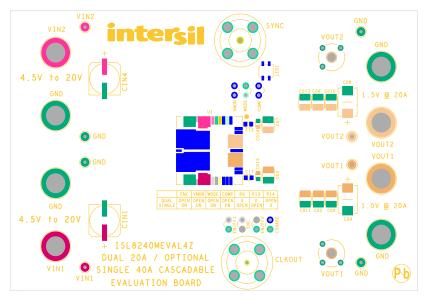


FIGURE 3. TOP SILKSCREEN

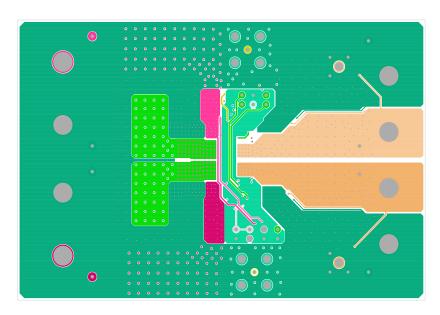


FIGURE 5. LAYER 2

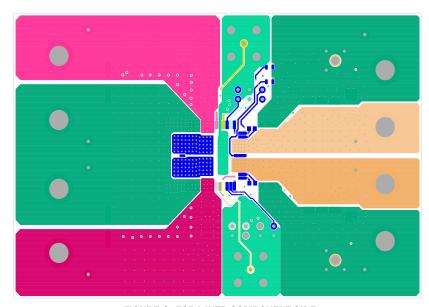


FIGURE 4. TOP LAYER COMPONENT SIDE

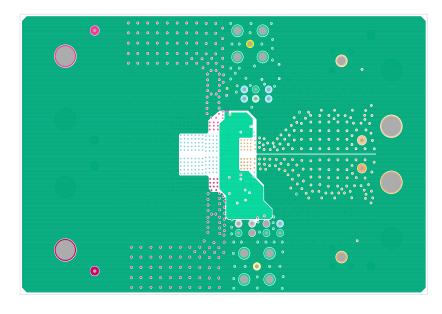


FIGURE 6. LAYER 3

# Layout (Continued)

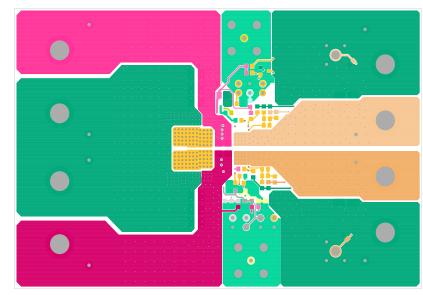


FIGURE 7. BOTTOM LAYER SOLDER SIDE

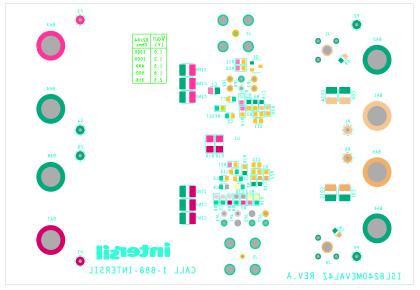


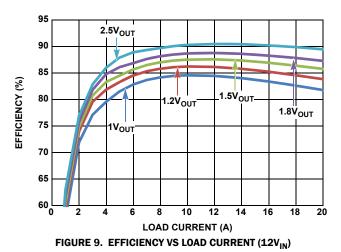
FIGURE 8. BOTTOM SILKSCREEN

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# **Bill of Materials**

| PART NUMBER          | REF DES                                       | QTY | VALUE  | TOL.<br>(%) | VOLTAGE    | POWER | PACKAGE TYPE | JEDEC TYPE            | MANUFACTURER | DESCRIPTION                   |
|----------------------|---|-----|--------|-------------|------------|-------|--------------|-----------------------|--------------|-------------------------------|
| 575-4                | BA1, BA2, BA3, BA4, BA5,<br>BA6, BA7, BA8     | 8   |        |             |            |       | CONN         | CON_BAN_575           |              |                               |
| GRM21BR71C475KA73L   | C1  | 1   | 4.7µF  | 10          | <b>16V</b> |       | 805          | CAP_0805              | Murata       | Ceramic Capacitor             |
| H1045-OPEN           | C2, C3, C6, C7                                | 4   | OPEN   |             | OPEN       |       | 603          | CAP_0603              | Generic      | Multilayer Capacitor          |
| H1045-00102-50V10    | C4, C5, C8, C9                                | 4   | 1000pF | 10          | 50V        |       | 603          | CAP_0603              | Generic      | Multilayer Capacitor          |
| H1045-OPEN           | C10, C11, C12, C13, C14, C17                  | 6   | OPEN   |             | OPEN       |       | 603          | CAP_0603              | Generic      | Multilayer Capacitor          |
| H1045-00102-16V10    | C15, C16                                      | 2   | 1000pF | 10          | <b>16V</b> |       | 603          | CAP_0603              | Generic      | Multilayer Capacitor          |
| H1082-00107-6R3V20-T | C01, C03, C05, C07, C011,<br>C012, C013, C014 | 8   | 100µF  | 20          | 6.3V       |       | 1210         | CAP_1210              | TDK          | Ceramic Chip Capacitor        |
| H1082-OPEN           | C02, C06, C09, C10                            | 4   | OPEN   |             | OPEN       |       | 1210         | CAP_1210              | Generic      | Ceramic Chip Capacitor        |
| 6TPF330M9L           | C04, C08                                      | 2   | 330µF  | 20          | 6.3V       |       | SMD          | CAP_7343_149          | Sanyo        | Tantalum Polymer<br>Capacitor |
| EEVHA1E331UP         | CIN1, CIN4                                    | 2   | 330µF  | 20          | 25V        |       | SMD          | CAPAE_315X402         | Panasonic    |                               |
| TMK325B7226MM-TR     | CIN2, CIN3, CIN5, CIN6,<br>CIN7, CIN8         | 6   | 22µF   | 20          | 25V        |       | 1210         | CAP_1210              | Taiyo Yuden  | Ceramic Chip Capacitor        |
| 131-4353-00          | J1, J4  | 2   |        |             |            |       | CONN         | TEK131-4353-00        |              |                               |
| 31-5329-52RFX        | J2, J5  | 2   |        |             |            |       | CONN         | CON_BNC_31_5329_52RFX |              |                               |
| JUMPER2_100          | JP1-JP7                                       | 7   |        |             |            |       | THOLE        | JUMPER-1              |              |                               |
| SSL-LXA3025IGC       | LED1  | 1   |        |             |            |       | SMD          | LED_3X2_5MM           |              |                               |
| 5002                 | P1, P2, P3, P4, P5, P6, P7,<br>P8             | 8   |        |             |            |       | THOLE        | MTP500X               |              |                               |
| 2N7002-7-F           | Q1  | 1   |        |             |            |       | S0T23        | S0T23                 |              |                               |
| H2511-01001-1/10W1   | R1, R3  | 2   | 1kΩ    | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-01501-1/10W1   | R2  | 1   | 1.5kΩ  | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-06650-1/10W1   | R4  | 1   | 665Ω   | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-06650-1/10W1   | R5, R7  | 2   | 16.5Ω  | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-06650-1/10W1   | R6, R8  | 2   | 4.12kΩ | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-06650-1/10W1   | R9, R10, R13, R20, R22                        | 5   | Ω0     | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2511-06650-1/10W1   | R11, R12                                      | 2   | 3.32kΩ | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| H2505-DNP-DNP-1      | R14, R15,R16, R21                             | 4   | OPEN   |             |            |       | 603          | RES_0603              |              | Chip Resistor                 |
| H2513-00R00-1/4W     | R18, R19                                      | 2   | Ω0     | 1           |            | 1/4W  | 1206         | RES_1206              |              | Chip Resistor                 |
| H2511-02373-1/10W1   | RFSET   | 1   | 237kΩ  | 1           |            | 1/10W | 603          | RES_0603              |              | Chip Resistor                 |
| ISL8240MIRZ          | U1  | 1   |        |             |            |       | QFN          |                       |              |                               |

# **ISL8240MEVAL4Z Performance**



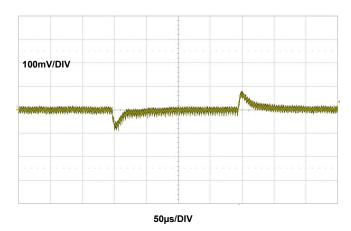


FIGURE 10. 1V $_{
m OUT}$  transient response, I $_{
m OUT}$  = 0A to 10A, F $_{
m SW}$  = 350KHZ LOAD CURRENT SLEW RATE 10A/MS

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